

General Purpose NPN Epitaxial Planar Transistor

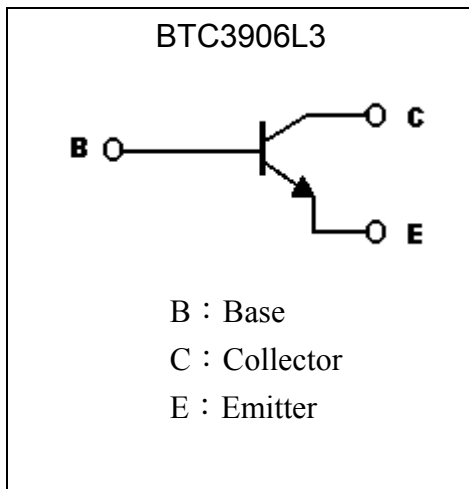
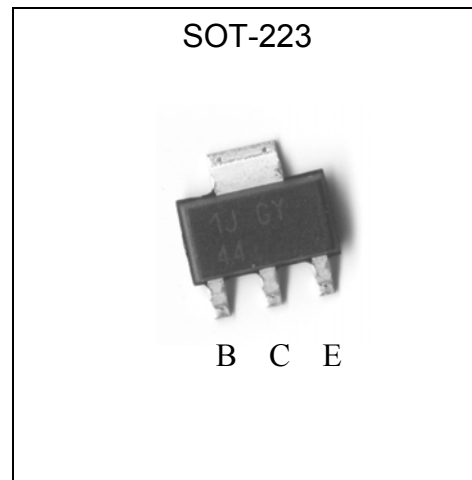
BTC3906L3

Description

The BTC3906L3 is designed for general purpose applications requiring high breakdown voltage.

Features

- High collector-emitter breakdown voltage. ($BV_{CEO}=160V @ I_C=1mA$)
- Complement to BTA1514L3

Symbol

Outline

Absolute Maximum Ratings ($T_a=25^{\circ}C$)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CB0}	180	V
Collector-Emitter Voltage	V_{CEO}	160	V
Emitter-Base Voltage	V_{EB0}	6	V
Collector Current	I_C	600	mA
Power Dissipation@ $T_c=25^{\circ}C$	P_d	5	W
Junction Temperature	T_j	150	$^{\circ}C$
Storage Temperature	T_{stg}	-55~+150	$^{\circ}C$

**Characteristics (Ta=25°C)**

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CB0}	180	-	-	V	I _C =100μA
BV _{CEO}	160	-	-	V	I _C =1mA
BV _{EBO}	6	-	-	V	I _E =10μA
I _{CB0}	-	-	50	nA	V _{CB} =120V
I _{EBO}	-	-	50	nA	V _{EB} =4V
*V _{CE(sat)1}	-	0.1	0.15	V	I _C =10mA, I _B =1mA
*V _{CE(sat)2}	-	-	0.2	V	I _C =50mA, I _B =5mA
*V _{BE(sat)1}	-	-	1	V	I _C =10mA, I _B =1mA
*V _{BE(sat)2}	-	-	1	V	I _C =50mA, I _B =5mA
*h _{FE1}	25	-	-	-	V _{CE} =5V, I _C =1mA
*h _{FE2}	60	-	-	-	V _{CE} =5V, I _C =10mA
*h _{FE3}	40	-	-	-	V _{CE} =5V, I _C =50mA
*h _{FE4}	52	-	390	-	V _{CE} =6V, I _C =2mA
f _T	100	-	-	MHz	V _{CE} =20V, I _C =10mA, f=100MHz
Cob	-	-	6	pF	V _{CB} =20V, I _E =0A, f=1MHz

*Pulse Test: Pulse Width ≤380μs, Duty Cycle ≤2%

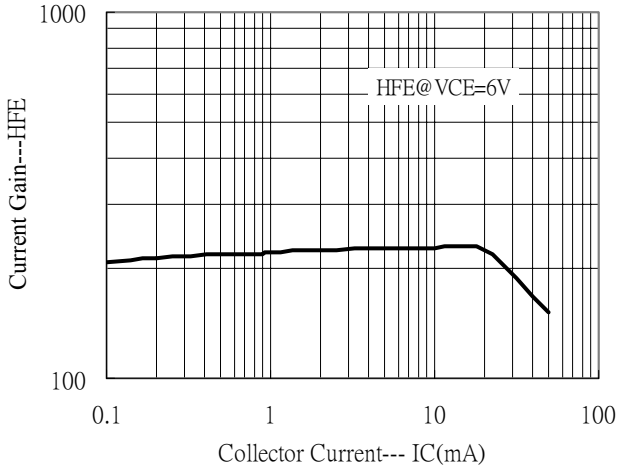
Classification Of h_{FE} 4

Rank	K	P	Q	R
Range	52~120	82~180	120~270	180~390

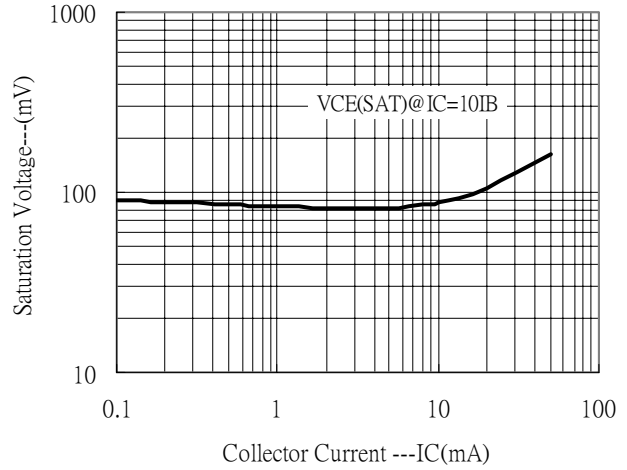


Characteristic Curves

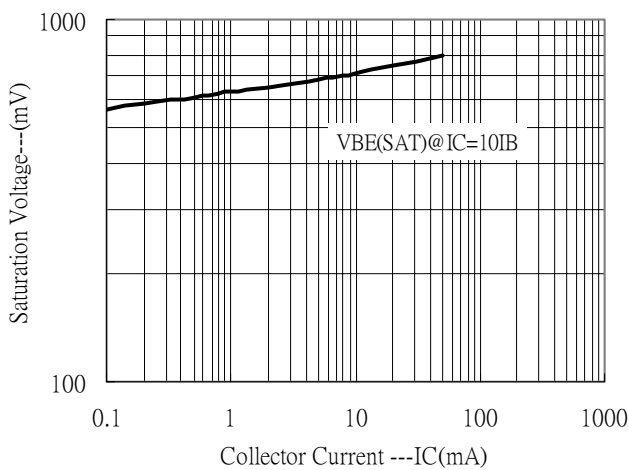
Current Gain vs Collector Current



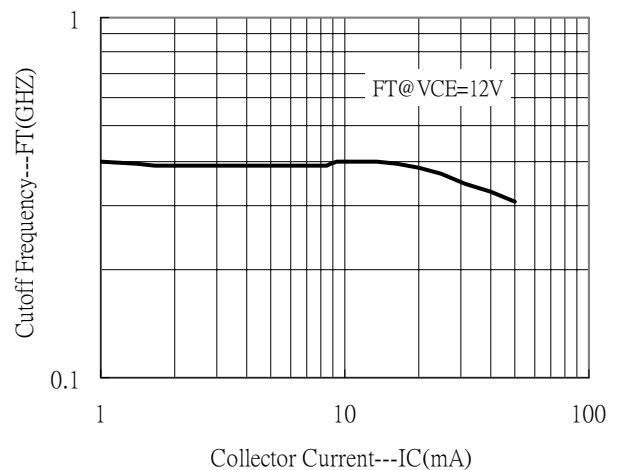
Saturation Voltage vs Collector Current



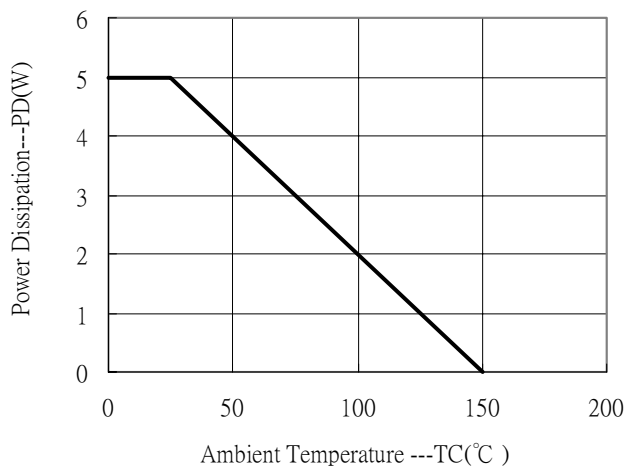
Saturation Voltage vs Collector Current



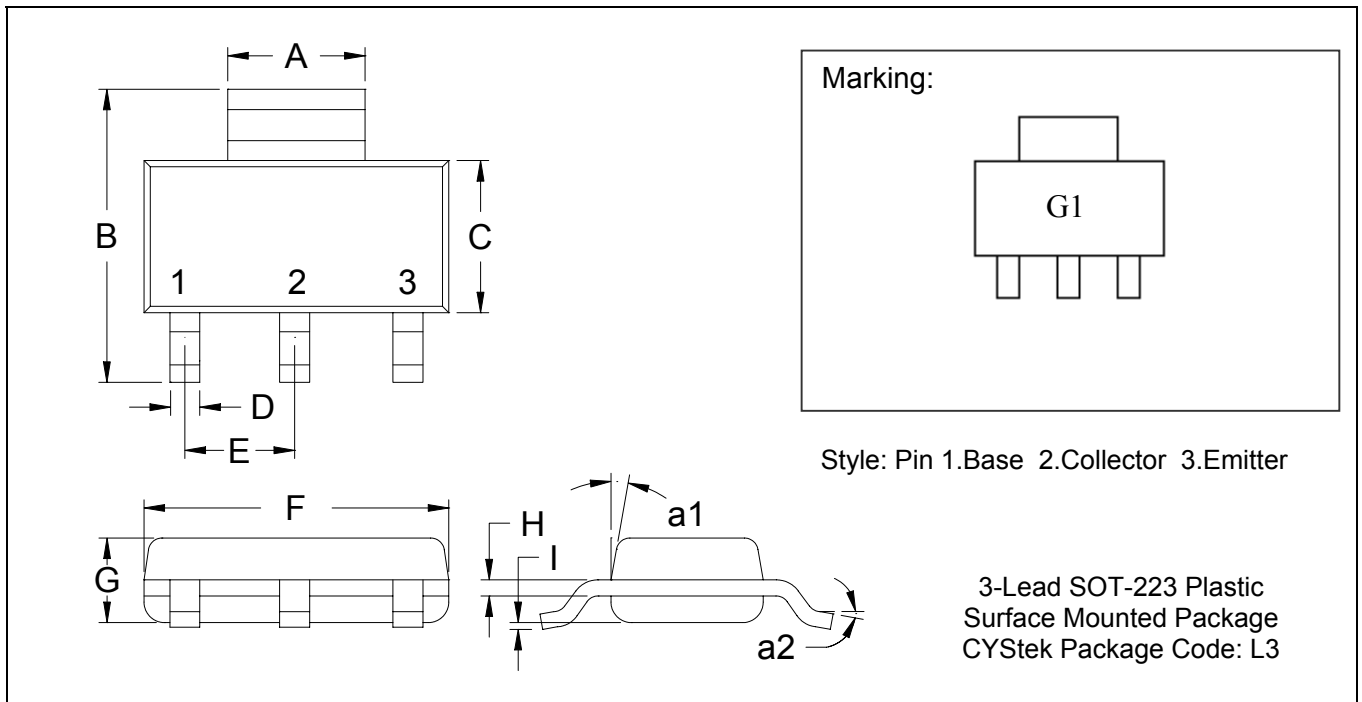
Cutoff Frequency vs Collector Current



Power Derating Curves



SOT-223 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1142	0.1220	2.90	3.10	G	0.0551	0.0709	1.40	1.80
B	0.2638	0.2874	6.70	7.30	H	0.0098	0.0138	0.25	0.35
C	0.1299	0.1457	3.30	3.70	I	0.0008	0.0039	0.02	0.10
D	0.0236	0.0315	0.60	0.80	a1	*13°	-	*13°	-
E	*0.0906	-	*2.30	-	a2	0°	10°	0°	10°
F	0.2480	0.2638	6.30	6.70					

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: 42 Alloy; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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